NSN 5961-01-282-7240

Fiig: A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-282-7240 **Inclosure Material:** Metal **Overall Length:** 0.320 inches **Overall Height:** 0.025 inches **Overall Width:** 0.320 inches **Component Name And Quantity:** 4 semiconductor device diode **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 0.25 forward voltage, dc all semiconductor device diode **Current Rating Per Characteristic:** 1.00 milliamperes source cutoff current preset all semiconductor device diode **Power Rating Per Characteristic:** 75.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No